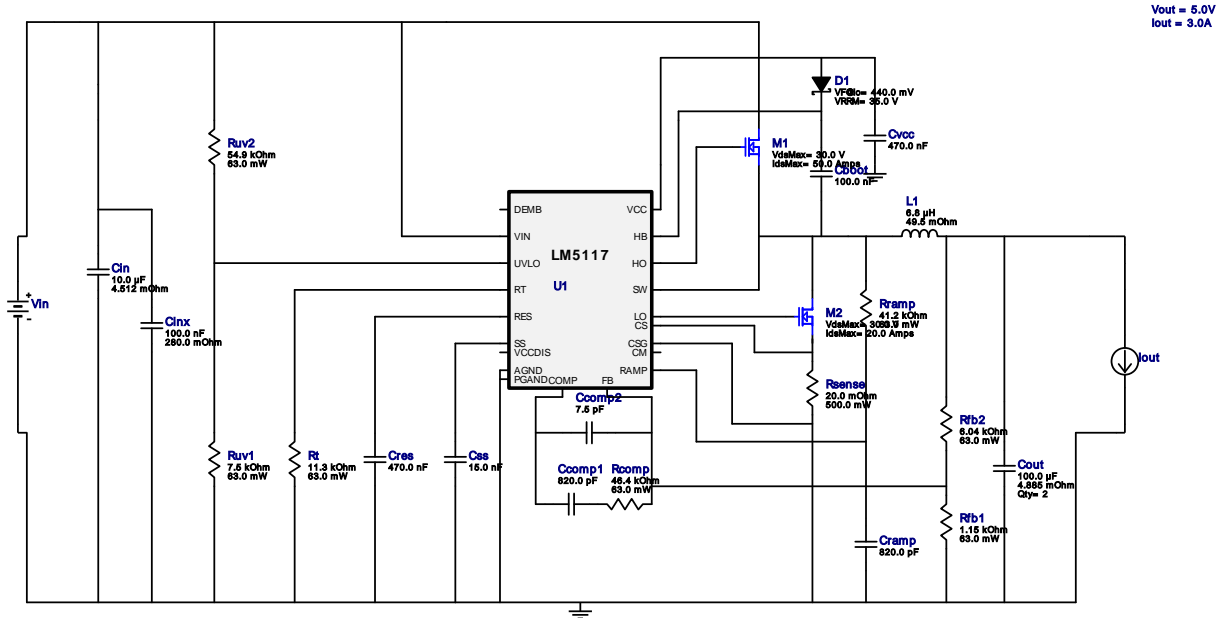















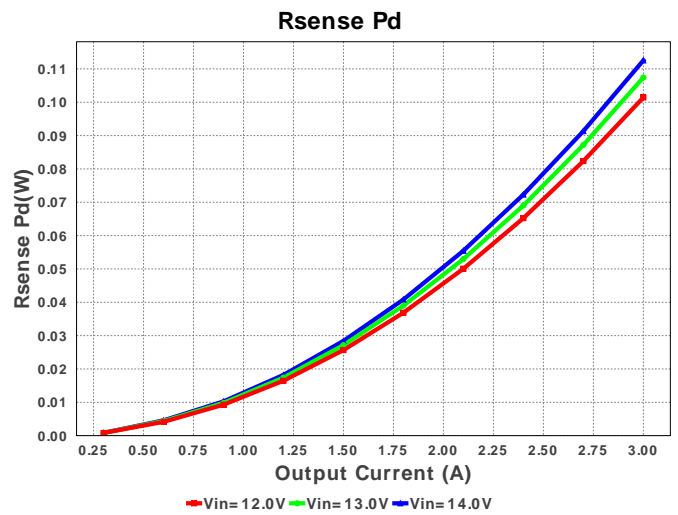
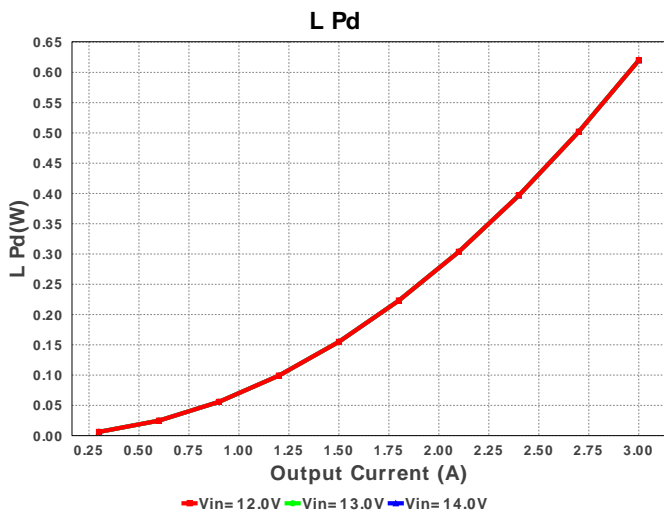
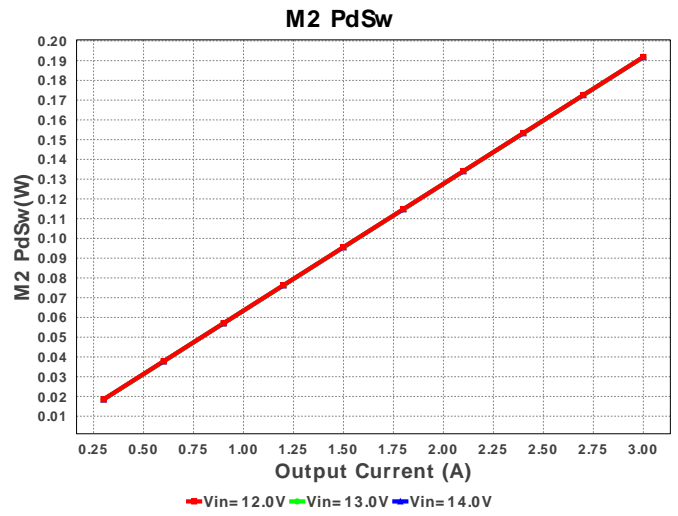
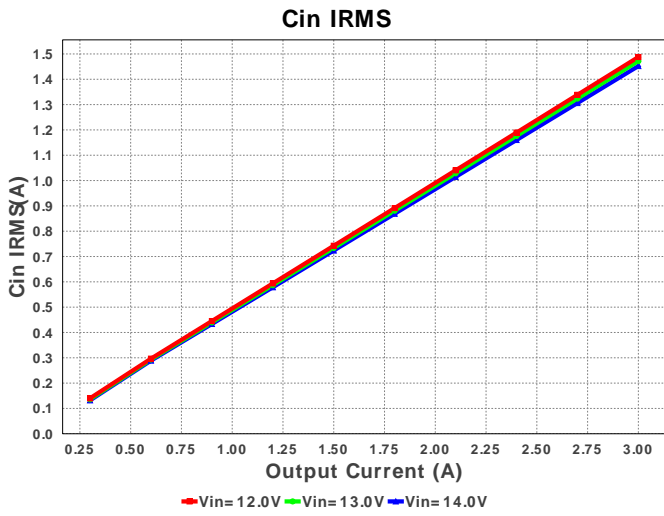
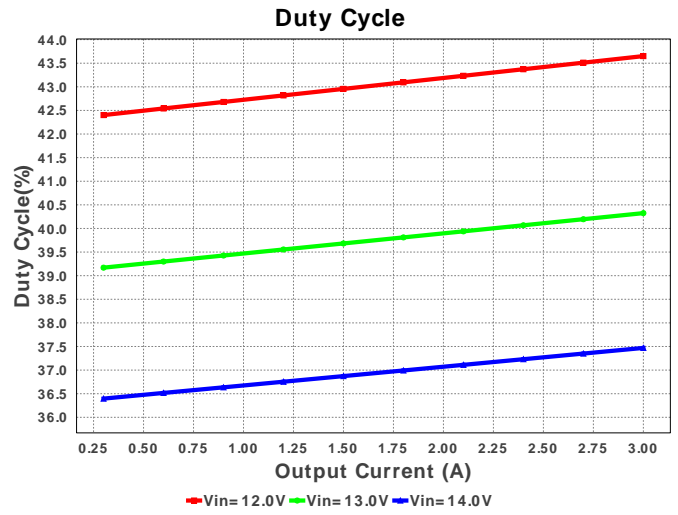
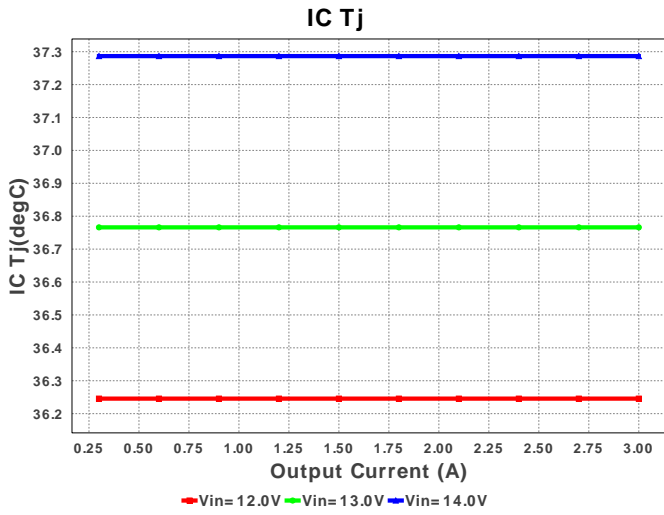


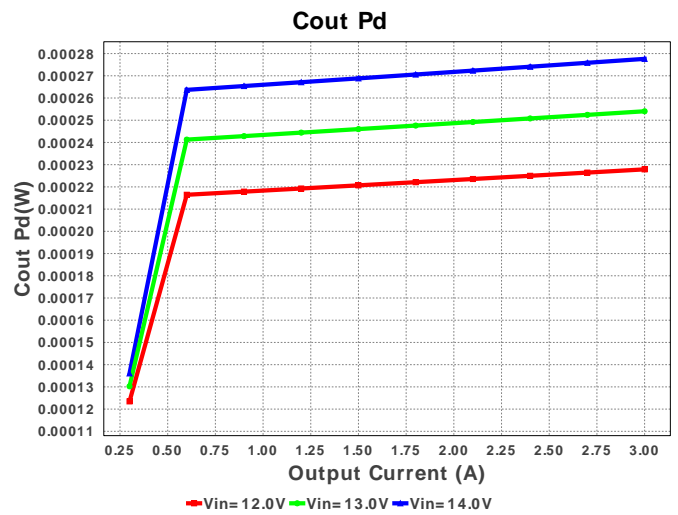
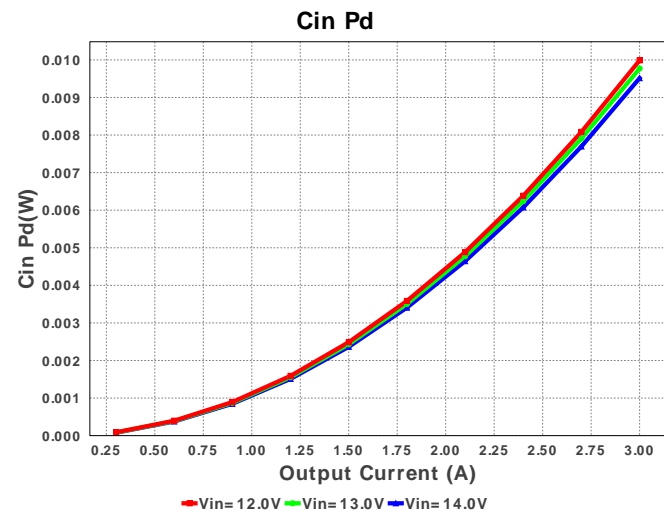
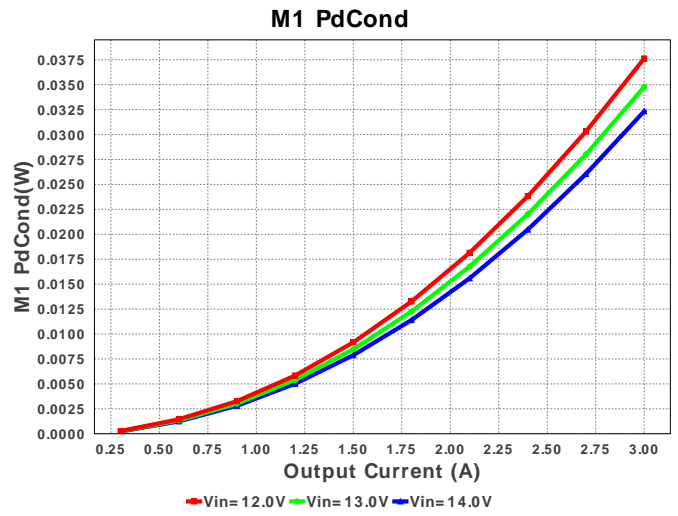
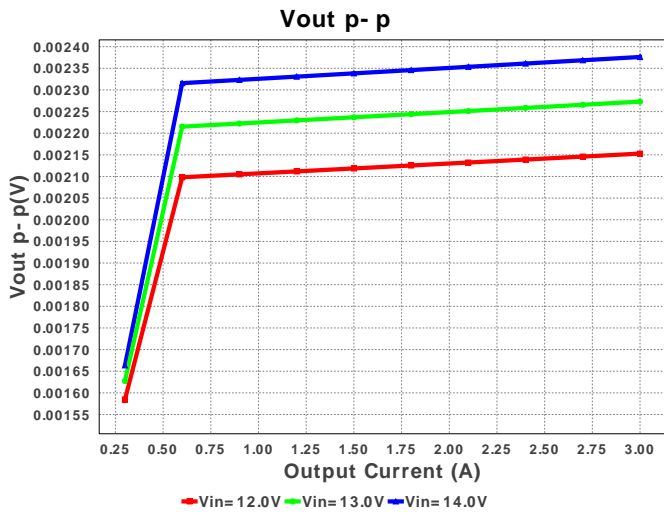
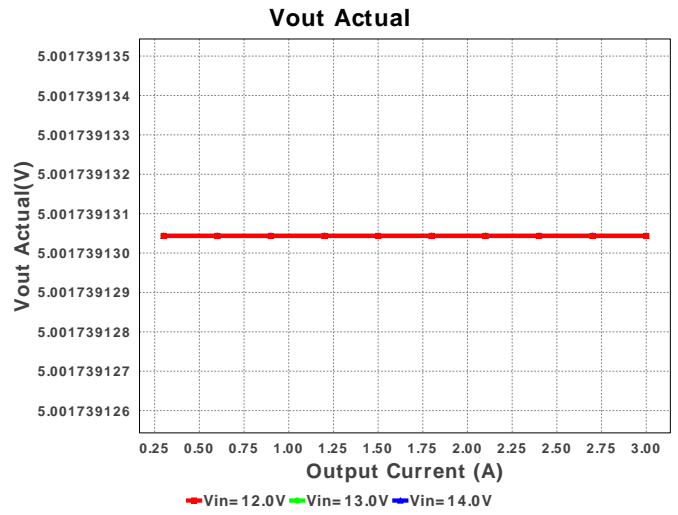
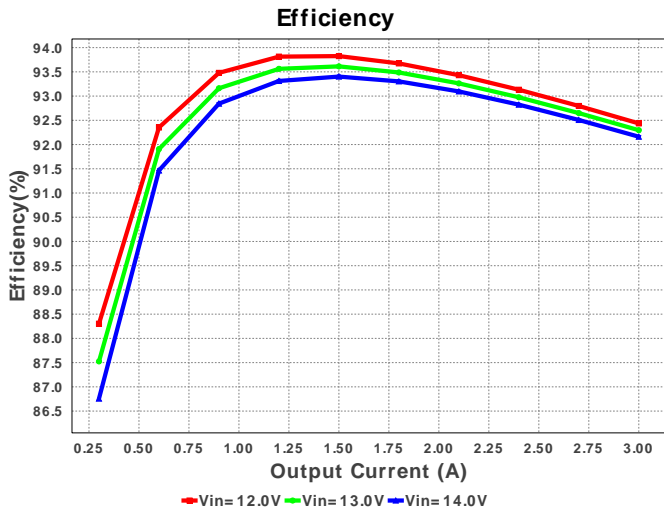
**WEBENCH® Design Report**

 Design : 4007980/14 LM5117PMHX/NOPB  
 LM5117PMHX/NOPB 12.0V-14.0V to 5.00V @ 3.0A

**Electrical BOM**

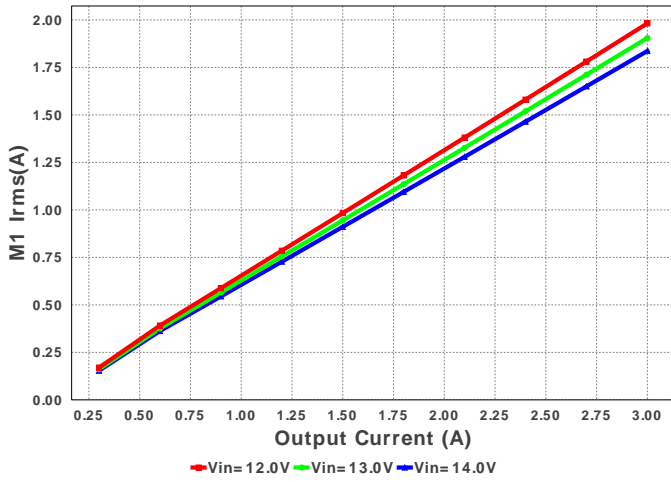
#	Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
1.	Cboot	MuRata	GRM155R61A104KA01D Series= X5R	Cap= 100.0 nF VDC= 10.0 V IRMS= 0.0 A	1	\$0.01	0402 3 mm <sup>2</sup>
2.	Ccomp1	Yageo America	CC0805KRX7R9BB821 Series= X7R	Cap= 820.0 pF VDC= 50.0 V IRMS= 0.0 A	1	\$0.01	0805 7 mm <sup>2</sup>
3.	Ccomp2	MuRata	GRM1555C1H7R5CA01D Series= C0G/NP0	Cap= 7.5 pF VDC= 50.0 V IRMS= 0.0 A	1	\$0.01	0402 3 mm <sup>2</sup>
4.	Cin	MuRata	GRM31CR61E106KA12L Series= X5R	Cap= 10.0 uF ESR= 4.512 mOhm VDC= 25.0 V IRMS= 2.447 A	1	\$0.05	1206_190 11 mm <sup>2</sup>
5.	Cinx	AVX	08053C104KAT2A Series= X7R	Cap= 100.0 nF ESR= 280.0 mOhm VDC= 25.0 V IRMS= 0.0 A	1	\$0.01	0805 7 mm <sup>2</sup>
6.	Cout	MuRata	GRM31CR60J107ME39L Series= X5R	Cap= 100.0 uF ESR= 4.885 mOhm VDC= 6.3 V IRMS= 4.4118 A	2	\$0.14	1206_190 11 mm <sup>2</sup>
7.	Cramp	Yageo America	CC0805KRX7R9BB821 Series= X7R	Cap= 820.0 pF VDC= 50.0 V IRMS= 0.0 A	1	\$0.01	0805 7 mm <sup>2</sup>
8.	Cres	MuRata	GRM155C80J474KE19D Series= X6S	Cap= 470.0 nF VDC= 6.3 V IRMS= 0.0 A	1	\$0.01	0402 3 mm <sup>2</sup>

#	Name	Manufacturer	Part Number	Properties	Qty	Price	Footprint
9.	Css	Yageo America	CC0805KRX7R9BB153 Series= X7R	Cap= 15.0 nF VDC= 50.0 V IRMS= 0.0 A	1	\$0.01	 0805 7 mm <sup>2</sup>
10.	Cvcc	MuRata	GRM155R61A474KE15D Series= X5R	Cap= 470.0 nF VDC= 10.0 V IRMS= 0.0 A	1	\$0.01	 0402 3 mm <sup>2</sup>
11.	D1	Bourns	CD0603-B0130L	VF@Io= 440.0 mV VRRM= 35.0 V	1	\$0.09	 Diode_0603 5 mm <sup>2</sup>
12.	L1	Bourns	SRP6540-6R8M	L= 6.8 µH DCR= 49.5 mOhm	1	\$0.49	 SRP6540 83 mm <sup>2</sup>
13.	M1	Texas Instruments	CSD17308Q3	VdsMax= 30.0 V IdsMax= 50.0 Amps	1	\$0.28	 TRANS_NexFET_Q3 18 mm <sup>2</sup>
14.	M2	Texas Instruments	CSD17578Q3A	VdsMax= 30.0 V IdsMax= 20.0 Amps	1	\$0.21	 TRANS_NexFET_Q3A 18 mm <sup>2</sup>
15.	Rcomp	Vishay-Dale	CRCW040246K4FKED Series= CRCW..e3	Res= 46.4 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
16.	Rfb1	Vishay-Dale	CRCW04021K15FKED Series= CRCW..e3	Res= 1.15 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
17.	Rfb2	Vishay-Dale	CRCW04026K04FKED Series= CRCW..e3	Res= 6.04 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
18.	Rramp	Vishay-Dale	CRCW040241K2FKED Series= CRCW..e3	Res= 41.2 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
19.	Rsense	Stackpole Electronics Inc	CSR1206FK20L0 Series= ?	Res= 20.0 mOhm Power= 500.0 mW Tolerance= 1.0%	1	\$0.10	 1206 11 mm <sup>2</sup>
20.	Rt	Vishay-Dale	CRCW040211K3FKED Series= CRCW..e3	Res= 11.3 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
21.	Ruv1	Vishay-Dale	CRCW04027K50FKED Series= CRCW..e3	Res= 7.5 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
22.	Ruv2	Vishay-Dale	CRCW040254K9FKED Series= CRCW..e3	Res= 54.9 kOhm Power= 63.0 mW Tolerance= 1.0%	1	\$0.01	 0402 3 mm <sup>2</sup>
23.	U1	Texas Instruments	LM5117PMHX/NOPB	Switcher	1	\$2.10	 PWP0020A 71 mm <sup>2</sup>

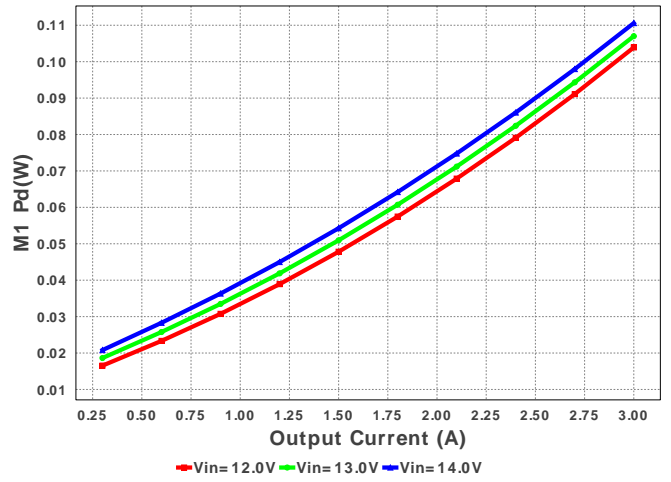




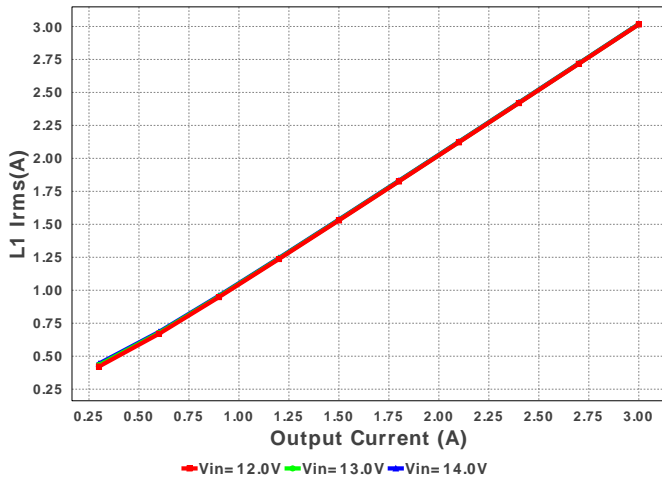
M1 Irms



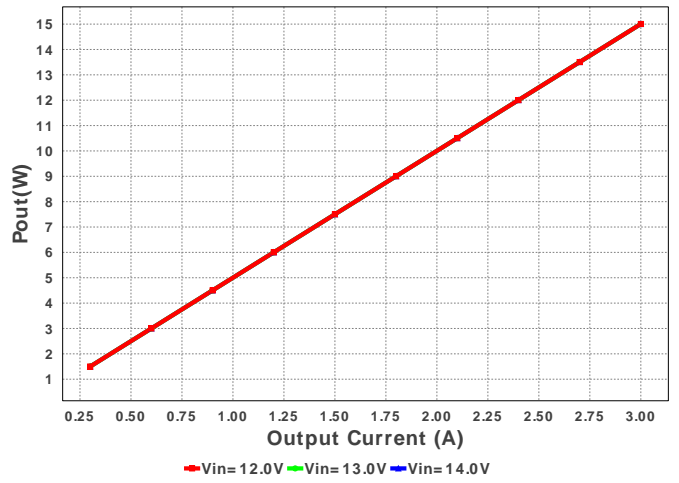
M1 Pd



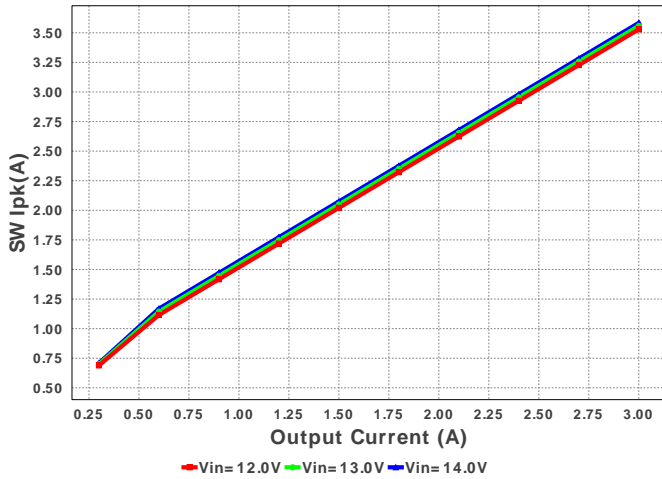
L1 Irms



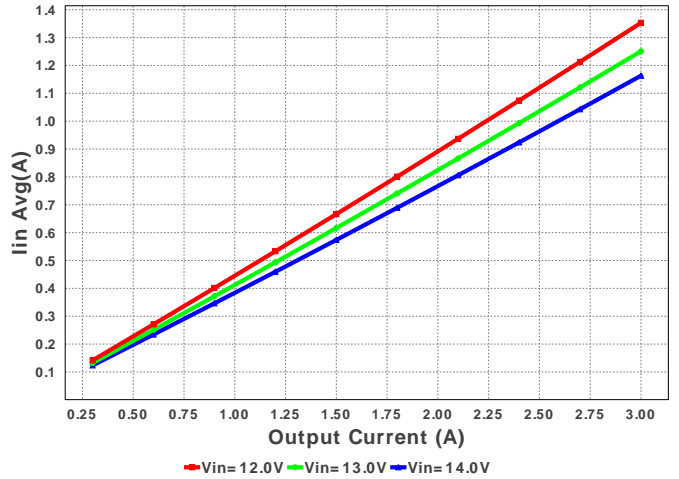
Pout

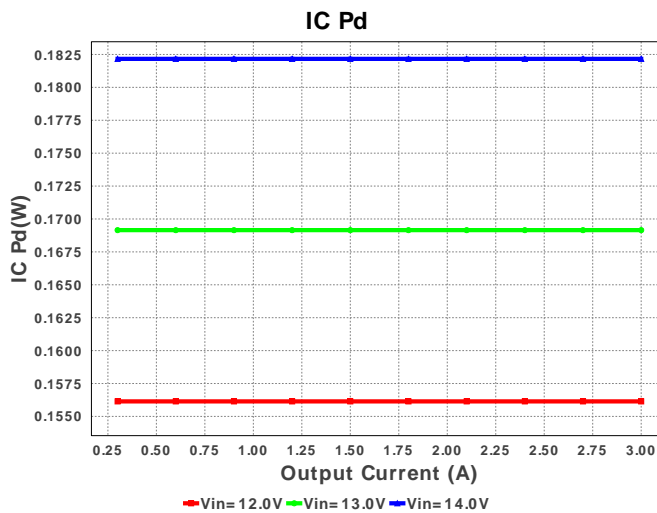
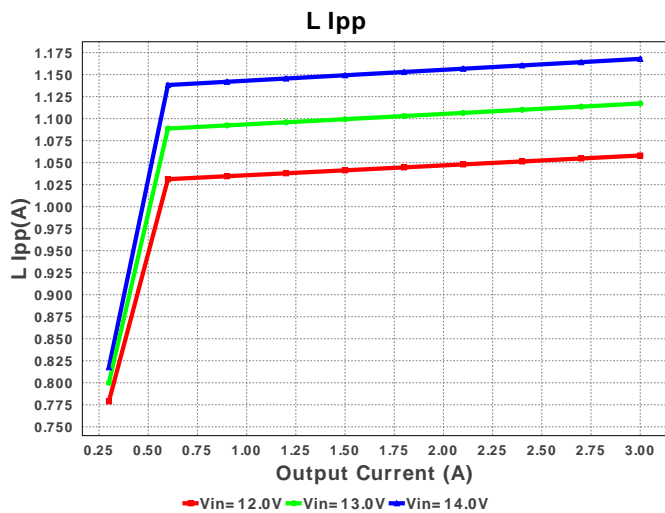
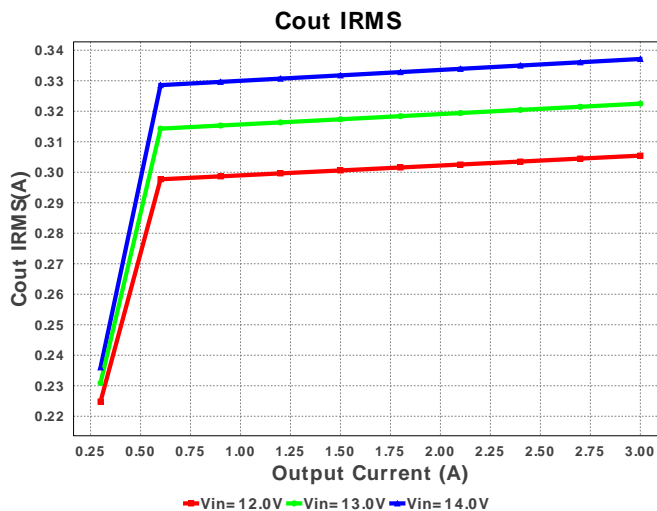
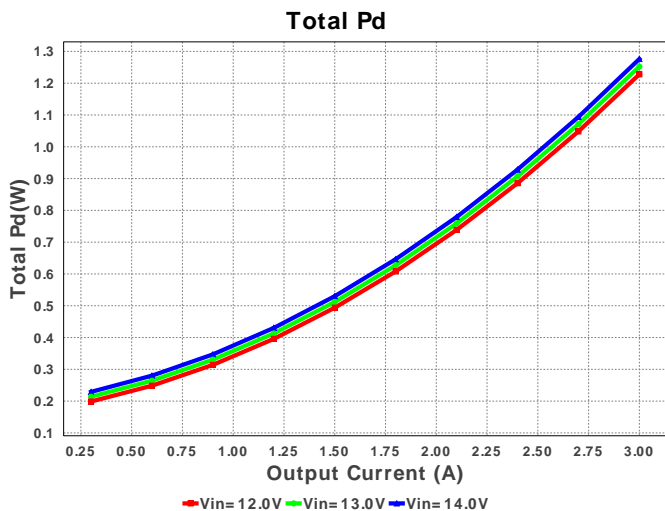
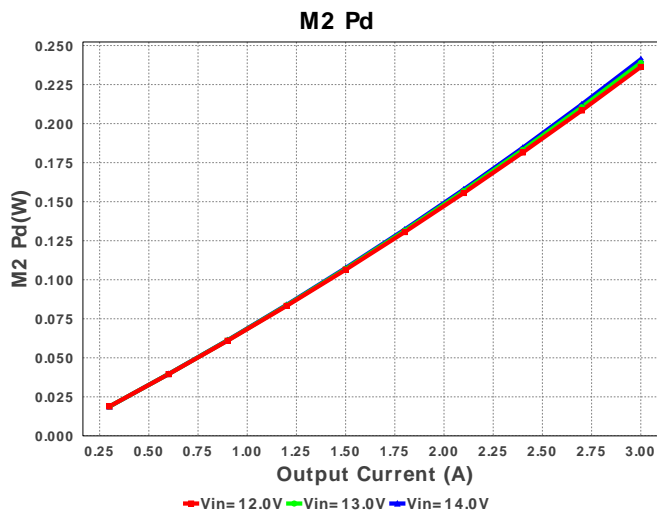
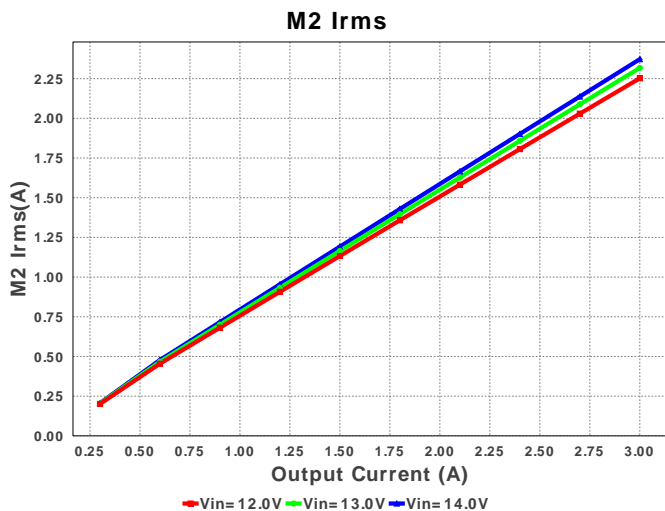


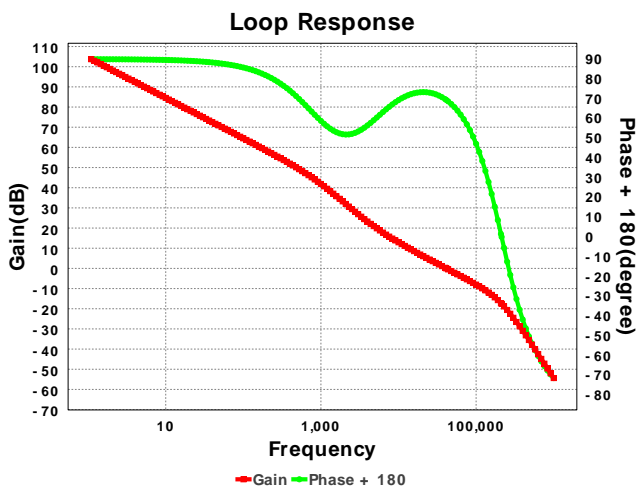
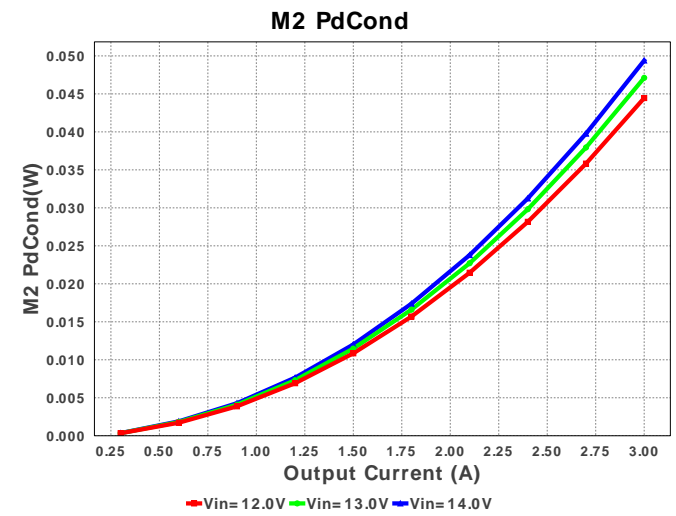
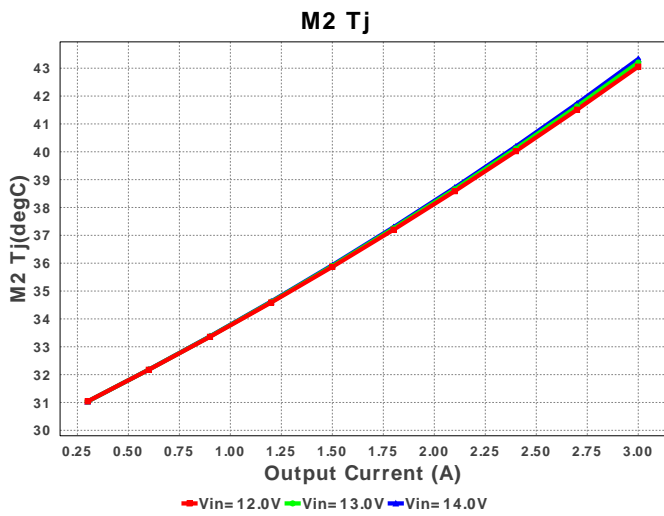
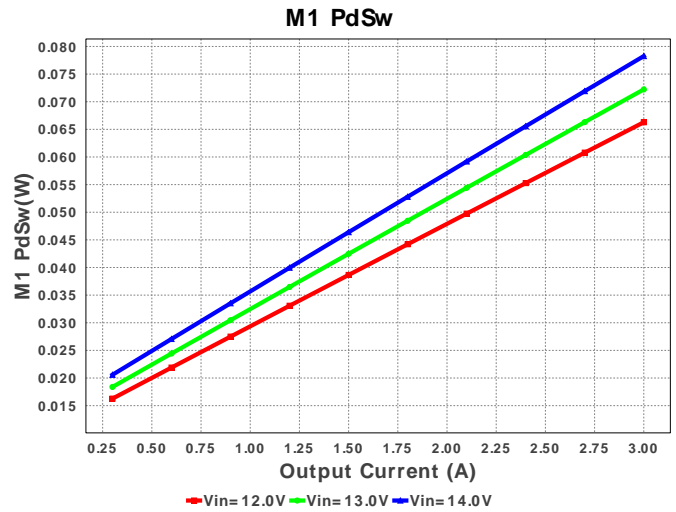
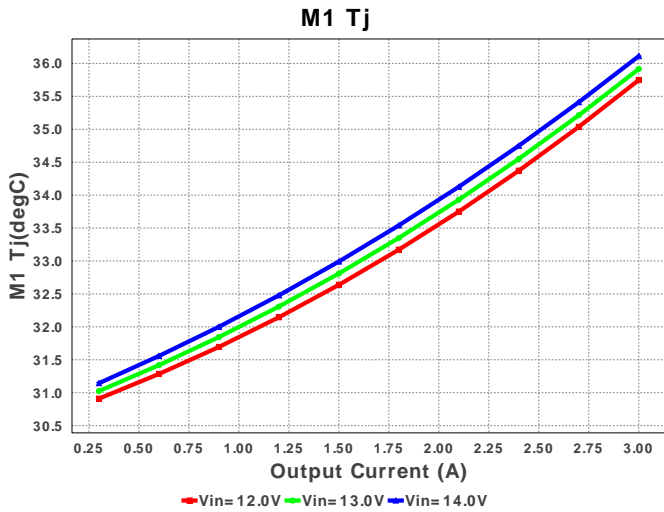
SW Ipk



Iin Avg







### Operating Values

#	Name	Value	Category	Description
1.	Cin IRMS	1.452 A	Current	Input capacitor RMS ripple current
2.	Cout IRMS	337.135 mA	Current	Output capacitor RMS ripple current
3.	Iin Avg	1.163 A	Current	Average input current
4.	L Ipp	1.168 A	Current	Peak-to-peak inductor ripple current
5.	L1 Irms	3.019 A	Current	Inductor ripple current
6.	M1 Irms	1.836 A	Current	MOSFET RMS ripple current
7.	M2 Irms	2.372 A	Current	MOSFET RMS ripple current
8.	SW Ipk	3.584 A	Current	Peak switch current
9.	BOM Count	24	General	Total Design BOM count
10.	FootPrint	300.0 mm <sup>2</sup>	General	Total Foot Print Area of BOM components
11.	Frequency	424.559 kHz	General	Switching frequency

#	Name	Value	Category	Description
12.	IC Tolerance	12.0 mV	General	IC Feedback Tolerance
13.	Mode	CCM	General	Conduction Mode
14.	Pout	15.005 W	General	Total output power
15.	Total BOM	\$3.75	General	Total BOM Cost
16.	Low Freq Gain	103.717 dB	Op_Point	Gain at 10Hz
17.	Vout Actual	5.002 V	Op_Point	Vout Actual calculated based on selected voltage divider resistors
18.	Vout OP	5.002 V	Op_Point	Operational Output Voltage
19.	Cross Freq	41.289 kHz	Op_point	Bode plot crossover frequency
20.	Duty Cycle	37.47 %	Op_point	Duty cycle
21.	Efficiency	92.153 %	Op_point	Steady state efficiency
22.	Gain Marg	-17.559 dB	Op_point	Bode Plot Gain Margin
23.	IC Tj	37.349 degC	Op_point	IC junction temperature
24.	IOUT_OP	3.0 A	Op_point	Iout operating point
25.	M1 Tj	36.111 degC	Op_point	M1 MOSFET junction temperature
26.	M2 Tj	43.331 degC	Op_point	M2 MOSFET junction temperature
27.	Phase Marg	69.331 deg	Op_point	Bode Plot Phase Margin
28.	VIN_OP	14.0 V	Op_point	Vin operating point
29.	Vout p-p	2.377 mV	Op_point	Peak-to-peak output ripple voltage
30.	Cin Pd	9.514 mW	Power	Input capacitor power dissipation
31.	Cout Pd	277.614 μW	Power	Output capacitor power dissipation
32.	IC Pd	183.713 mW	Power	IC power dissipation
33.	L Pd	619.922 mW	Power	Inductor power dissipation
34.	M1 Pd	110.59 mW	Power	M1 MOSFET total power dissipation
35.	M1 PdCond	32.335 mW	Power	M1 MOSFET conduction losses
36.	M1 PdSw	78.255 mW	Power	M1 MOSFET switching losses
37.	M2 Pd	241.166 mW	Power	M2 MOSFET total power dissipation
38.	M2 PdCond	49.395 mW	Power	M2 MOSFET conduction losses
39.	M2 PdSw	191.771 mW	Power	M2 MOSFET switching losses
40.	Rsense Pd	112.554 mW	Power	LED Current Rsns Power Dissipation
41.	Total Pd	1.278 W	Power	Total Power Dissipation
42.	Vout Tolerance	3.222 %		Vout Tolerance based on IC Tolerance (no load) and voltage divider resistors if applicable

## Design Inputs

#	Name	Value	Description
1.	Iout	3.0	Maximum Output Current
2.	VinMax	14.0	Maximum input voltage
3.	VinMin	12.0	Minimum input voltage
4.	Vout	5.0	Output Voltage
5.	base_pn	LM5117	Base Product Number
6.	source	DC	Input Source Type
7.	Ta	30.0	Ambient temperature

## Design Assistance

1. Outline The LM5117 is a synchronous buck controller intended for step-down regulator applications from a high voltage or widely varying input supply. The control method is based upon current mode control utilizing an emulated current ramp. Current mode control provides inherent line feed-forward, cycle-by-cycle current limiting and ease of loop compensation. The use of an emulated control ramp reduces noise sensitivity of the pulse-width modulation circuit, allowing reliable control of very small duty cycles necessary in high input voltage applications. External Vcc An output voltage derived bias supply can be applied to the VCC pin to reduce the controller power dissipation at higher input voltage. This can also relax constraints on the driver supply current if your external source can supply more than the LM5117 internal regulator. Please see Datasheet for more information. Diode Emulation A fully synchronous buck regulator implemented with a freewheel MOSFET rather than a diode has the capability to sink current from the output in certain conditions such as light load, over-voltage or pre-bias startup. The LM5117 provides a diode emulation feature that can be enabled to prevent reverse (drain to source) current flow in the low side free-wheel MOSFET.

2. **LM5117 Product Folder** : <http://www.ti.com/product/LM5117> : contains the data sheet and other resources.

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**You should completely validate and test your design implementation to confirm the system functionality for your application prior to production.**

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